



# **Photo IC for optical link**

S12512-01SR

## Receiver photo IC for DC to 1 Mbps optical link

The S12512-01SR is a receiver photo IC for plastic optical fiber (POF) communication. It has monolithically integrated PIN photodiode and signal processing circuit. It features small size and strong resistance to electromagnetic induction noise. High-speed optical communication is possible over a wide range from DC up to 1 Mbps. It provides CMOS-compatible digital output.

#### Features

- Receiver photo IC
- DC to 1 Mbps data communications
- Monolithic photo IC featuring strong resistance to electromagnetic induction noise
- **Digital output (CMOS) Digital output (CMOS)**
- Low current consumption

#### Applications

- Data transmission in harsh, noisy environments, such as in FA, OA, and digital audio
- High-speed, short-distance data transmission
- Highly bursty data transmission

#### **■** Absolute maximum ratings (Ta=25 °C, unless otherwise noted)

Parameter	Symbol	Condition	Value	Unit
Supply voltage	Vcc		-0.5 to +4.0	V
Output voltage	Vo		-0.5 to Vcc + 0.5	V
Power dissipation*1	Pmax		250	mW
Operating temperature	Topr	No dew condensation*2	-20 to +85	°C
Storage temperature	Tstg	No dew condensation*2	-40 to +85	°C
Soldering conditions	Tsol		230 °C, within 5 s, at least 1.5 mm away from lead roots	-

<sup>\*1:</sup> Power dissipation decreases at a rate of 1.75 mW/°C above Ta=25 °C.

Note: Exceeding the absolute maximum ratings even momentarily may cause a drop in product quality. Always be sure to use the product within the absolute maximum ratings.

#### **Recommended operating conditions**

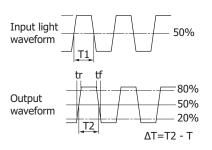
Parameter	Symbol	Min.	Тур.	Max.	Unit
Supply voltage	Vcc	3.135	3.3	3.465	V
High level output current	Ioh	-4	-	0	mΛ
Low level output current	Iol	0	-	4	mA

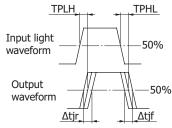
<sup>\*2:</sup> When there is a temperature difference between a product and the surrounding area in high humidity environment, dew condensation may occur on the product surface. Dew condensation on the product may cause deterioration in characteristics and reliability.

#### **■** Electrical and optical characteristics (Ta=25 °C, Vcc=3.135 to 3.465 V, unless otherwise noted)

	Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit
Data rate		fD	Biphase signal (NRZ conversion)	DC	-	1	Mbps
Current consum	ption	Icc	No optical input	-	-	2	mA
Maximum reception level		Pi max	Peak value*3	0	-	-	dBm
Minimum reception level		Pi min	Peak value, Pe=10 <sup>-7*3</sup>	-	-	-25	dBm
	High level output voltage	Voh	Ioh=-150 μA	2.7	-	-	V
Output voltage	Low level output voltage	Vol	Iol=1.6 mA	-	-	0.4	V
Output voitage	Rise time	tr	20% to 80%*4 *5	-	-	100	ns
	Fall time	tf	20% to 80%*4 *5	-	-	100	ns
Pulse width disto	Pulse width distortion		*3 *4 *5	-250	-	+250	ns
Jitter		∆tj	*3 *4 *5	-	-	200	ns

- \*3: A signal generated by a Hamamatsu's standard signal generator is assumed for the optical input signal.
- \*4: For the input signal, a 10 Mbps pseudo-random biphase signal is assumed.
- \*5: CL=5 pF (including parasitic capacitance of probe, connector, and printed circuit board)



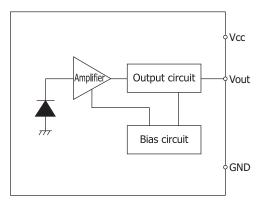


Parameter	Symbol	Measurement method
Rising edge jitter	Δtjr	Set the trigger to PPG CLK, and measure the jitter in the rising edge of the output.
Falling edge jitter	Δtjf	Set the trigger to PPG CLK, and measure the jitter in the falling edge of the output.
Jitter	Δtj	Set $\Delta tj$ to the larger of the two jitter values: $\Delta tjr$ and $\Delta tjf.$

KPICC0250EA

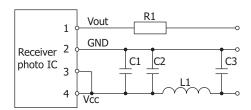
Note: Connect a  $0.1~\mu\text{F}$  bypass capacitor within 3 mm of this element's lead (between Vcc and GND). In addition, connect a  $10~\mu\text{F}$  capacitor. Align the center axes of the fiber and package lens, and make the gap between the fiber and the optical reference plane of the lens surface 0.1~mm.

#### **Block diagram**



KPICC0304EA

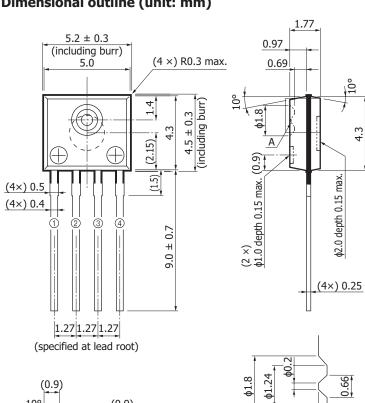
#### Connection example



Symbol	Component	Constant	Rating	Remarks
R1	Resistor	50 Ω to 150 Ω	60 mW or more	For overcurrent protection
L1	Inductance	0.1 µH	50 mA or more	
C1	Capacitor	0.1 μF	10 V or more	Bypass capacitor for noise suppression Connect near the lead (3 mm or less).
C2	Capacitor	10 μF	10 V or more	Bypass capacitor for noise suppression
C3	Capacitor	10 μF	10 V or more	Bypass capacitor for noise suppression

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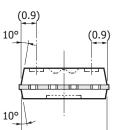
#### **►** Dimensional outline (unit: mm)



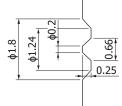
Pin no.	S12512-01SR
1	Vout
2	GND
3	Vcc
4	Vcc

Tolerance unless otherwise noted: ±0.1, ±2° Shaded area indicates burr. Values in parentheses indicate reference values.

Standard packing type Plastic tray (100 pcs/tray) Material: PVC (conductive)



5.0



Enlarged view of A

KPICA0103EA



### Photo IC for optical link

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#### Related information

www.hamamatsu.com/sp/ssd/doc\_en.html

- Precautions
- · Disclaimer
- · Metal, ceramic, plastic products

Information described in this material is current as of May 2018.

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